

# Ultrahigh Green and Red Optical Gain Cross Sections from Solutions of Colloidal Quantum Well Heterostructures

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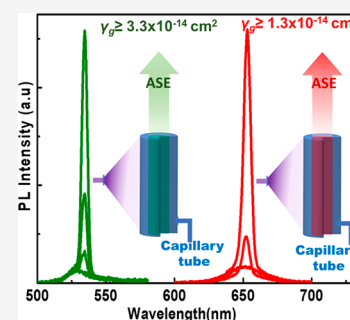
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**ABSTRACT:** We demonstrate amplified spontaneous emission (ASE) in solution with ultralow thresholds of 30  $\mu\text{J}/\text{cm}^2$  in red and of 44  $\mu\text{J}/\text{cm}^2$  in green from engineered colloidal quantum well (CQW) heterostructures. For this purpose, CdSe/CdS core/crown CQWs, designed to hit the green region, and CdSe/CdS@Cd<sub>x</sub>Zn<sub>1-x</sub>S core/crown@gradient-alloyed shell CQWs, further tuned to reach the red region by shell alloying, were employed to achieve high-performance ASE in the visible range. The net modal gain of these CQWs reaches 530  $\text{cm}^{-1}$  for the green and 201  $\text{cm}^{-1}$  for the red, 2–3 orders of magnitude larger than those of colloidal quantum dots (QDs) in solution. To explain the root cause for ultrahigh gain coefficient in solution, we show for the first time that the gain cross sections of these CQWs is  $\geq 3.3 \times 10^{-14} \text{ cm}^2$  in the green and  $\geq 1.3 \times 10^{-14} \text{ cm}^2$  in the red, which are two orders of magnitude larger compared to those of QDs.



Colloidal quantum wells (CQWs) present an excellent platform as gain medium owing to their solution processability, wide tunability of emission color,<sup>1–4</sup> giant oscillator strength,<sup>1,5</sup> large gain cross section,<sup>6</sup> slow Auger rates,<sup>7–9</sup> and ultranarrow emission profiles.<sup>1,3,10</sup> Especially the giant gain cross section and slow Auger recombination of CQWs make them extremely attractive candidates for optical gain studies and applications as these are the critical factors for satisfying the gain condition.<sup>11</sup> Lasing and amplified spontaneous emission (ASE) with ultralow thresholds<sup>2,7,8,12–15</sup> and large net modal gains<sup>7,14,16</sup> from solid films of close-packed CQWs have been widely studied. Although a solution-based gain medium can be highly advantageous because of the enhanced photostability owing to constant replenishment of the gain medium by the flux of nanocrystals and flexibility of incorporation into optical cavities, there are only very few reports of optical gain in solution using colloidal nanocrystals.<sup>6,17–20</sup> This is primarily due to the low concentration of gain media possible in solution, limiting the feasible levels of gain coefficients. While thin solid films of nanocrystals may lead to lower thresholds and larger modal gains due to the increased density of gain media, such films are more likely to suffer from surface roughness affecting the waveguiding and optical confinement,<sup>21–23</sup> nonradiative losses due to Förster resonance energy transfer (FRET) and homo-FRET,<sup>24,25</sup> and reproducibility of the identical samples.

In-solution optical gain can be achieved straightforwardly by employing a simple glass tube<sup>17</sup> or a cuvette<sup>6,18</sup> serving possibly as a cavity and a host along with highly concentrated nanocrystal solution serving as a gain medium. In this approach, uniform gain media in a cavity can be achieved robustly and reproducibly, and loss mechanisms, such as

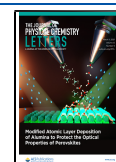
nonradiative homo-FRET and scattering of light due to aggregations of nanocrystals, are conveniently suppressed. Such a gain medium can be utilized in microfluidic networks to achieve on-chip lasing for optical sensing and detection.<sup>26–30</sup> Despite the foreseeable advantages of CQWs, including the modal gain reaching levels 1 order of magnitude larger than those of the quantum dots and nanorods,<sup>16</sup> slow Auger rates,<sup>7–9,31</sup> and gain cross sections 3 orders of magnitude larger than the quantum dots,<sup>6</sup> there is only one previously reported work on CQW-based optical gain in solution to date, which was achieved by multiphoton pumping using a cuvette-based Fabry–Perot resonator.<sup>6</sup>

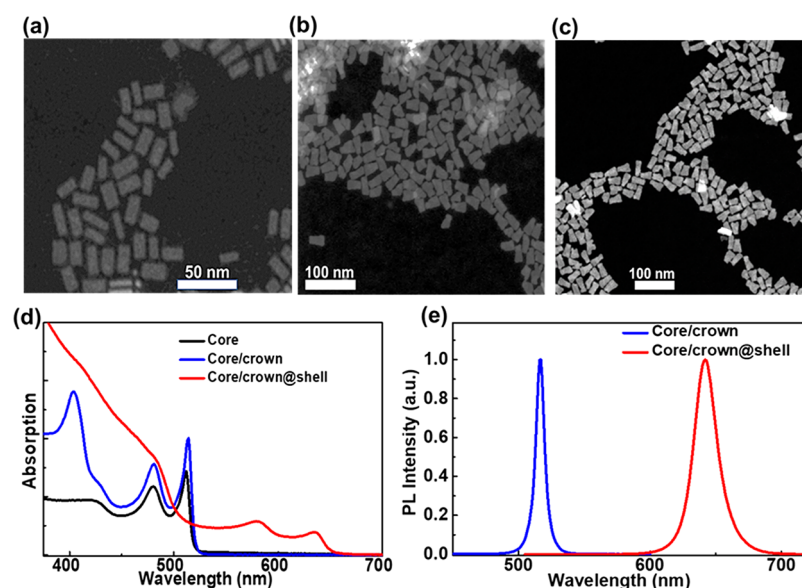
Here, we present the achievement of in-solution ASE from green-emitting CdSe/CdS core/crown CQWs and red CdSe/CdS@Cd<sub>x</sub>Zn<sub>1-x</sub>S core/crown@gradient-alloyed shell CQWs enabling ultralow thresholds of 44 and 30  $\mu\text{J}/\text{cm}^2$ , respectively, in solution. The net modal gains of green CdSe/CdS core/crown CQWs and red CdSe/CdS@Cd<sub>x</sub>Zn<sub>1-x</sub>S core/crown@gradient-alloyed shell CQWs at a concentration of  $1.7 \times 10^{16} \text{ cm}^{-3}$  reach  $\sim 530$  and  $\sim 201 \text{ cm}^{-1}$ , respectively. In addition, we report for the first time the gain cross section of these heterostructures of CQWs, which are found to be  $\geq 3.3 \times 10^{-14} \text{ cm}^2$  for the green-emitting CdSe/CdS core/crown CQWs and  $\geq 1.3 \times 10^{-14} \text{ cm}^2$  for the red-emitting CdSe/CdS@Cd<sub>x</sub>Zn<sub>1-x</sub>S

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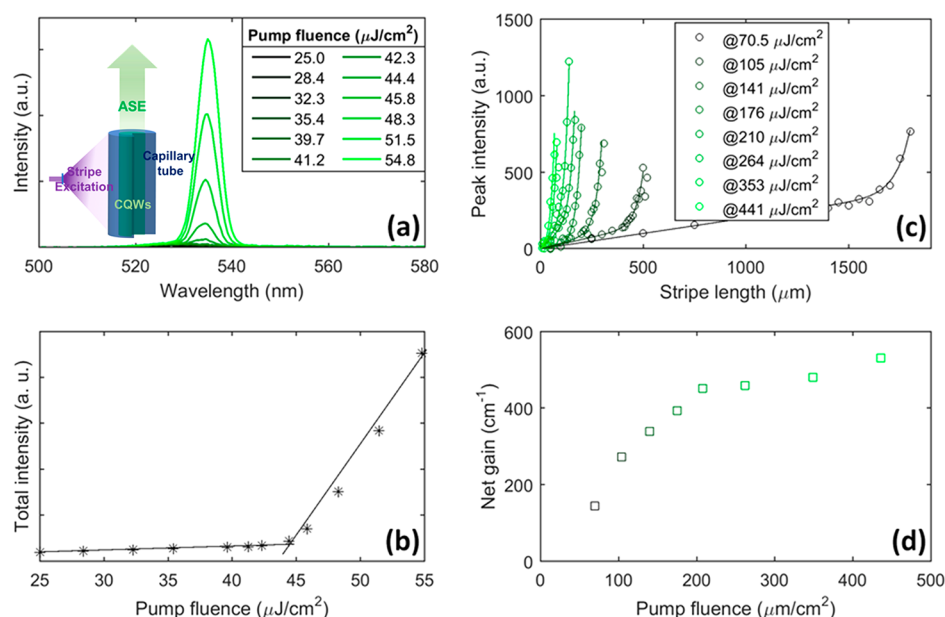
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**Figure 1.** TEM images of (a) 4 ML CdSe, (b) 4 ML CdSe/CdS core/crown, and (c) 12 ML CdSe/CdS@Cd<sub>x</sub>Zn<sub>1-x</sub>S core/crown@gradient-alloyed shell CQWs. (d) Absorption spectra of CdSe, CdSe/CdS core/crown, and CdSe/CdS@Cd<sub>x</sub>Zn<sub>1-x</sub>S core/crown@gradient-alloyed shell CQWs. (e) PL spectra of CdSe/CdS core/crown and CdSe/CdS@Cd<sub>x</sub>Zn<sub>1-x</sub>S core/crown@gradient-alloyed shell CQWs.



**Figure 2.** Optical gain performance of in-solution CdSe/CdS core/crown CQWs. (a) Collected optical spectra at different pump fluences. Inset of panel a shows a schematic of CQW solution in the capillary tube optically pumped using stripe geometry for ASE measurements. (b) Emission intensity as a function of the pump fluence. (c) Emission intensity as a function of the excitation stripe length. (d) Extracted net gain coefficients as a function of the pump fluence.

core/crown@gradient-alloyed shell CQWs. These obtained gain cross sections are 2 orders of magnitude larger than those of QDs<sup>11,17</sup> and hence show the vast potential of CQWs as an in-solution optical gain medium.

For the purpose of systematic study of optical gain in solution, we synthesized CdSe/CdS core/crown CQWs<sup>32</sup> to hit the green spectral range and CdSe/CdS@Cd<sub>x</sub>Zn<sub>1-x</sub>S core/crown@gradient-alloyed shell CQWs<sup>33</sup> to reach the red range, both using high-quality 4-monolayer (ML) CdSe CQWs as the seeds. Transmission electron microscopy (TEM) images of the CdSe core CQWs and CdSe/CdS core/crown CQWs are shown in panels a and b of Figure 1, respectively. The lateral

area was measured to be  $\sim 150 \text{ nm}^2$  for the core CQWs and  $\sim 350 \text{ nm}^2$  for the core/crown CQWs.

To further obtain the CdSe/CdS@Cd<sub>x</sub>Zn<sub>1-x</sub>S core/crown@gradient-alloyed shell CQWs, 4 ML thick gradient alloyed shell of Cd<sub>x</sub>Zn<sub>1-x</sub>S was grown on the previously synthesized CdSe/CdS core/crown CQWs to push the emission peak toward red.<sup>33</sup> Details of the synthesis of CQWs are provided in the Supporting Information. Owing to the gradient alloyed shell of Cd<sub>x</sub>Zn<sub>1-x</sub>S, charge carriers feel soft potential confinement in the vertical dimension,<sup>33</sup> which is also highly desirable for optical gain applications because of the suppression of Auger

recombination.<sup>34</sup> A representative TEM image of these core/crown@gradient-alloyed shell CQWs is presented in Figure 1c.

The absorption profiles of the CdSe core, CdSe/CdS core/crown, and CdSe/CdS@Cd<sub>x</sub>Zn<sub>1-x</sub>S core/crown@gradient-alloyed shell CQWs are given in Figure 1d. The absorption cross sections of CdSe/CdS core/crown and CdSe/CdS@Cd<sub>x</sub>Zn<sub>1-x</sub>S core/crown@gradient-alloyed shell CQWs are  $1.1 \times 10^{-13}$  cm<sup>2</sup> and  $2.9 \times 10^{-13}$  cm<sup>2</sup>, respectively, at 400 nm, which were calculated using a method provided in our previous publication.<sup>35</sup> The intrinsic absorption coefficients  $\mu_i(\lambda)$  of the CdSe/CdS core/crown and CdSe/CdS@Cd<sub>x</sub>Zn<sub>1-x</sub>S core/crown@gradient-alloyed shell CQWs, which are obtained by dividing the absorption cross sections at the wavelength of interest by the physical volume of the CQWs, are  $1.96 \times 10^5$  and  $2.1 \times 10^4$  cm<sup>-1</sup>, respectively, at their heavy hole absorption peak. It is worth mentioning that the intrinsic absorption is an important parameter showing the gain capability of a material.<sup>36</sup> The photoluminescence (PL) spectra of CdSe/CdS core/crown and CdSe/CdS@Cd<sub>x</sub>Zn<sub>1-x</sub>S core/crown@gradient-alloyed shell CQWs in solution are shown in Figure 1e. The PL peak of the core/crown CQWs is at ~517 nm (in solution) with a full width at half-maximum (fwhm) of 8 nm, while that of CdSe/CdS@Cd<sub>x</sub>Zn<sub>1-x</sub>S core/crown@gradient-alloyed shell CQWs (in solution) is at ~642 nm with a fwhm of ~21 nm.

To explore the ASE performance of our CQWs in solution, CQWs dispersed in toluene were inserted into a capillary tube having an inner diameter of 300 μm with the help of capillary force. The higher boiling point (compared to most nonpolar solvents, such as commonly used hexane), the lower volatility, and the relatively high refractive index of toluene make it our choice of solvent. Figure 2a shows pump-fluence dependence of the ASE spectra from CdSe/CdS core/crown CQWs. The sharp ASE peak can be observed at 534.2 nm with a fwhm of 4.3 nm at room temperature on the red side of the spontaneous emission for the pump fluences above the threshold. This red shift of ASE (~5 nm) with respect to the spontaneous emission confirms multiexcitonic gain.<sup>37</sup> This sort of red shift in ASE is desirable for optical gain because this hinders self-absorption.<sup>7,38</sup> Total emission intensity as a function of the pump fluence for the green-emitting CQWs is presented in Figure 2b. Using this data, the ASE threshold is calculated to be 44 μJ/cm<sup>2</sup>, which is lower than any previously reported ASE threshold in solution for nanocrystals. Previously, the best reported threshold in solution for colloidal nanocrystals was ~105 μJ/cm<sup>2</sup> from CsPbBr<sub>3</sub> perovskite nanocrystals.<sup>18</sup>

We used the variable-stripe-length (VSL) method<sup>39</sup> to determine the modal gain of CQWs in solution at various pump fluences higher than the optical gain threshold. Figure 2c displays total emission intensities at different pump fluences as a function of the stripe length. Figure 2d presents the pump-dependent net modal gain coefficient at various pump fluences obtained from the fittings presented in Figure 2c. As can be seen in Figure 2d, the net modal gain increases linearly at lower fluences above the threshold and saturates around ~530 cm<sup>-1</sup>. Although these net modal gains are nearly 1 order of magnitude lower than those of their solid films<sup>7,16</sup> because of lower concentration of CQWs, these net modal gains are similar to the net modal gains of solid films of quantum dots and nanorods<sup>40-43</sup> and 2–3 orders of magnitude larger than that of QDs in solution.<sup>17</sup>

The gain cross section per CQW ( $\gamma_g$ ) can be calculated by

$$g_{\text{net}} = C \times \Gamma \times \gamma_g - \alpha \quad (1)$$

where  $C$  is the concentration of CQWs,  $\Gamma$  the optical confinement factor, and  $\alpha$  the optical loss coefficient.<sup>6</sup> In our case,  $C$  is  $\sim 1.7 \times 10^{16}$  cm<sup>-3</sup> (~28.3 μM) in toluene;  $g_{\text{net}}$  is known at different pump fluences as presented in Figure 2d, and  $\Gamma$  is calculated by numerically solving the supported optical modes, as will be discussed next. Here, we assume that the net modal gain is close to the modal gain ( $g$ ) for optical gain in solution.<sup>6</sup> In fact, our net modal gain levels (530 cm<sup>-1</sup> for CdSe/CdS core/crown CQWs and 201 cm<sup>-1</sup> for CdSe/CdS@Cd<sub>x</sub>Zn<sub>1-x</sub>S core/crown@shell CQWs) are much larger than even the loss coefficient from films of CQWs (~10 cm<sup>-1</sup>),<sup>22</sup> which are expected to suffer larger loss in film compared to in solution. In addition, we added the term  $\Gamma$  into the eq 1 to account for the optical confinement factor in the active optical gain media.

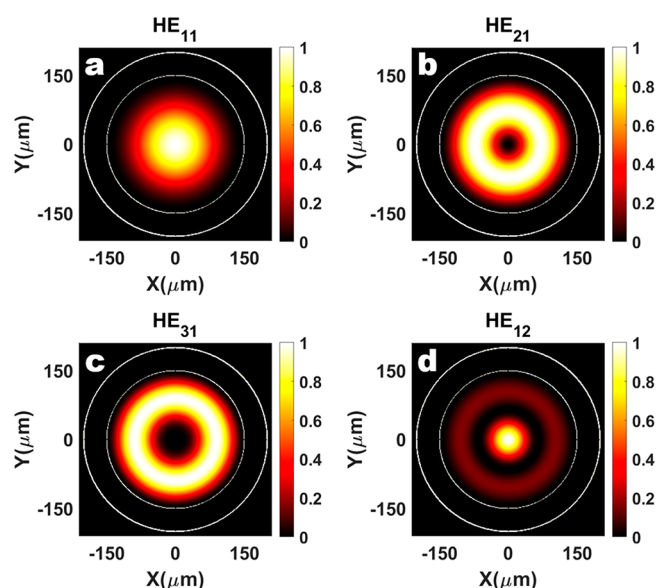
Here,  $\Gamma$  was calculated by obtaining the electrical field distribution in our system.  $\Gamma$  for a mode is defined as the ratio of the modal power inside the excited portion of the gain media to the total modal power:

$$\Gamma = \frac{\int_{\text{excited gain region}} \frac{1}{2} \text{Re}\{\vec{E} \times \vec{H}^*\} \cdot \hat{z} \, dx \, dy}{\int_{-\infty}^{\infty} \frac{1}{2} \text{Re}\{\vec{E} \times \vec{H}^*\} \cdot \hat{z} \, dx \, dy} \quad (2)$$

where  $\vec{E}$  and  $\vec{H}$  are the electric and magnetic fields of the specified mode, respectively. The gain cross section ( $\gamma_g$ ) can be found by computing  $\Gamma$  for the modes that are guided and confined. The modal power distributions for the first four modes (HE<sub>11</sub>, HE<sub>21</sub>, HE<sub>31</sub>, and HE<sub>12</sub>) for CdSe/CdS core/crown CQWs are presented in Figure 3a–d. The confinement factor peaks at 0.94 for HE<sub>11</sub> because of strong overlap with the excitation. On the basis of this maximal  $\Gamma$ , we computed the minimum gain cross section of CdSe/CdS core/crown CQWs using the modal gain value of 530 cm<sup>-1</sup> and the concentration of  $1.7 \times 10^{16}$  cm<sup>-3</sup>. The obtained value of gain cross section for CdSe/CdS core/crown CQWs is  $\geq 3.3 \times 10^{-14}$  cm<sup>2</sup>, which is 2 orders of magnitude larger than the gain cross section of QDs<sup>17</sup> having gain profiles saturating approximately twice of their thresholds, suggesting a limited number of carrier species contributing gain in the case of QDs. We attribute this extremely large gain cross section of CQWs to the high number of density of states in the CQWs.

Figure 4a presents the pump-fluence dependence of ASE spectra from the solution of CdSe/CdS@Cd<sub>x</sub>Zn<sub>1-x</sub>S core/crown@gradient-alloyed shell CQWs. In these CQWs, the spontaneous emission peaks at 651.9 nm with a fwhm of 29.0 nm. As the pump intensity increases, a sharp peak emerges at 653.0 nm with a fwhm of 6.0 nm and ultimately surpasses the PL spectrum at stronger pump fluences. The reduced red shift of ASE in this sample compared to that of the core/crown one can be attributed to the multiexcitonic gain with quasi-type-II band alignment profile. Total emission intensity as a function of the pump fluence is given in Figure 4b. The ASE threshold for these red-emitting CQWs is 30 μJ/cm<sup>2</sup>, which is lower than that of the green core/crown CQWs. This reduction in the gain threshold can be attributed to the further efficient suppression of Auger recombination in these alloyed-shell CQW heterostructures compared to the core/crown CQWs as a result of the graded alloying providing a soft confinement potential.<sup>7,34</sup> Figure 4c shows total emission intensities at



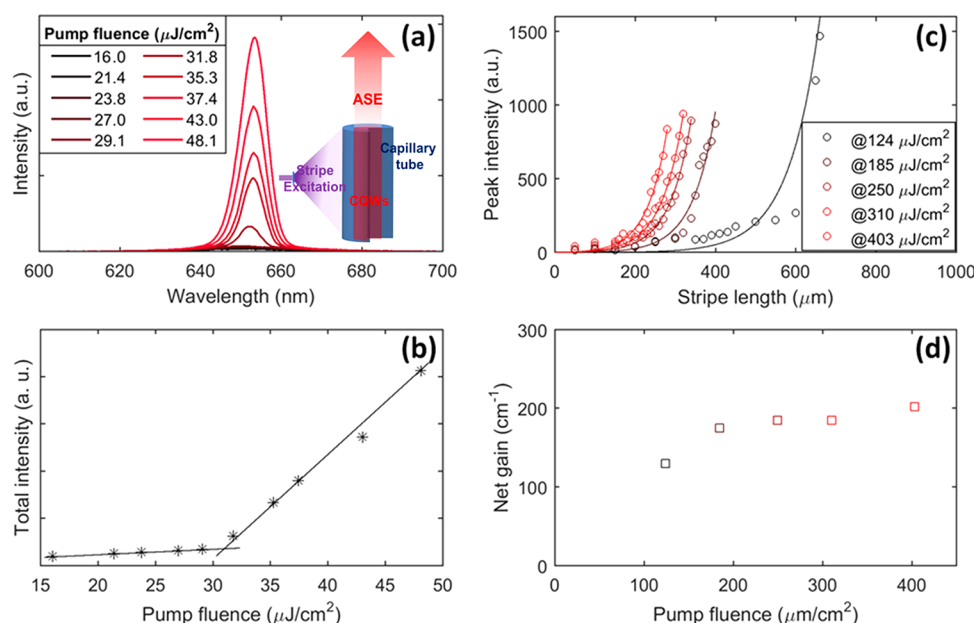


**Figure 3.** (a–d) Modal guided power distributions at 534 nm for the first four modes. The boundaries of the fiber are indicated with white concentric rings with the large ring ( $r = 200 \mu\text{m}$ ) corresponding to the air–cladding boundary and the small ring ( $r = 150 \mu\text{m}$ ) corresponding to the cladding–core boundary. Because of the large fiber parameter  $V$  and a similar refractive index of our CQW solutions, the calculated profiles at 653 and 534 nm are practically identical. The reason behind the near-unity confinement factor for  $\text{HE}_{11}$  is easily understood from the regional overlap between mode and the excitation (see Figure S3).

different pump fluences as a function of the stripe length, and the net modal gain coefficients at various pump fluences obtained from the fittings given in Figure 4c are presented in Figure 4d. As shown in Figure 4d, the net modal gain saturates around  $201 \text{ cm}^{-1}$  at a pump fluence of  $\sim 350 \mu\text{J}/\text{cm}^2$ . This

maximum net modal gain from these red CQWs in solution is 2 orders of magnitude higher than that of CdZnS/ZnS alloyed-core/shell QDs<sup>17</sup> and similar to that of core/shell CQWs.<sup>6</sup> Modal characteristics of the red-emitting CQWs are identical to CdSe/CdS core/crown CQWs because of the large fiber parameter  $V$  and similar refractive index of CQW solutions, and hence, both CQW solutions share the same  $\Gamma$  value of 0.94 at the ASE peak wavelength. For these red CQWs, the gain cross section is found to be  $\geq 1.3 \times 10^{-14} \text{ cm}^2$ . However, the gain cross section of these core/crown@gradient-alloyed shell CQWs is lower than that of core/crown CQWs ( $\sim 3.3 \times 10^{-14} \text{ cm}^2$ ). This is also reflected by the lower absorption coefficient of the core/crown@gradient-alloyed shell CQWs compared to the core/crown CQWs. This can be explained by the quasi type-II band alignment of thicker core/crown@gradient-alloyed shell CQWs, which effectively reduces the oscillator strength of the transitions in the core/crown@gradient-alloyed shell CQWs. On the other hand, the intriguingly lower threshold of the core/crown@gradient-alloyed shell CQWs is dominantly dictated by their larger absorption cross section at the excitation wavelength and stronger suppression of Auger recombination as compared to the core/crown CQWs.

In summary, we demonstrated ASE in solution using CdSe/CdS core/crown CQWs designed to emit in green and CdSe/CdS@Cd<sub>x</sub>Zn<sub>1-x</sub>S core/crown@gradient-alloyed shell CQWs tuned to emit in red dispersed in toluene with ultralow thresholds of 44 and  $30 \mu\text{J}/\text{cm}^2$ , respectively. The net modal gain coefficients of these green and red CQWs reach  $\sim 530$  and  $\sim 201 \text{ cm}^{-1}$ , respectively, at a concentration of  $\sim 1.7 \times 10^{16} \text{ cm}^{-3}$ , which are 2–3 orders of magnitude larger than that of QDs in solution.<sup>17</sup> The gain cross sections of the green CdSe/CdS core/crown CQWs and the red CdSe/CdS@Cd<sub>x</sub>Zn<sub>1-x</sub>S core/crown@gradient-alloyed shell CQWs are  $\geq 3.3 \times 10^{-14} \text{ cm}^2$  and  $\geq 1.3 \times 10^{-14} \text{ cm}^2$ , respectively. The obtained gain cross sections are 2 orders of magnitude larger than the gain cross section of QDs and can be attributed to the higher



**Figure 4.** Optical gain performance of in-solution CdSe/CdS@Cd<sub>x</sub>Zn<sub>1-x</sub>S core/crown@gradient-alloyed shell CQWs. (a) Collected optical spectra at different pump fluences. The inset of panel a displays a schematic of CQW solution in the capillary tube pumped using stripe geometry for ASE measurements. (b) Emission intensity as a function of the pump fluence. (c) Emission intensity as a function of the excitation stripe length. (d) Extracted net gain coefficients as a function of the pump fluence.

available number of density of states in CQWs. These solution-processed CQWs with their exceptional properties as a solution-based optical gain medium present extraordinary opportunities for the design and implementation of solution-based lasers, which can be integrated conveniently and intimately into microfluidic devices designed for sensing and imaging applications.

## ■ ASSOCIATED CONTENT

### ■ Supporting Information

The Supporting Information is available free of charge at <https://pubs.acs.org/doi/10.1021/acs.jpclett.0c03836>.

Synthesis of CdSe/CdS core/crown CQWs and CdSe/CdS@Cd<sub>x</sub>Zn<sub>1-x</sub>S core/crown@gradient-alloyed shell CQWs, time-resolved PL measurements, details of the optical gain experiments, and numerical calculations for optical confinement factor (PDF)

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### Notes

The authors declare no competing financial interest.

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